1 Supplementary Information for

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Damp-heat stable and efficient perovskite solar cells and mini-modules with *t*BP-free hole-transporting layer

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25 Experimental Section

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27 Materials

Fluorine-doped tin oxide on glass (FTO) was purchased from Asahi. Hydrogen peroxide (H₂O₂, 28 electronic grade), ethanol (EtOH, 95%, special grade), and ethyl ether (99.5%, special grade) 29 30 were purchased from SAMCHUN. Hydrochloride (HCl, 37 wt% in water) was purchased from Chemical Co. Methylammonium chloride (MACl, for synthesis), N,N-31 Junsei dimethylformamide (DMF, anhydrous 99.8%), dimethyl sulfoxide (DMSO, >99.5%), 2-32 propanol (IPA, anhydrous, 99.5%), 2-methoxyethanol (2-ME, anhydrous, 99.8%), acetonitrile 33 (anhydrous, 99.8%), chlorobenzene (CB, anhydrous, 99.8%), titanium diisopropoxide 34 bis(acetylacetonate) (Ti(acac)₂, 75 wt% in IPA), potassium chloride (KCl, ACS reagent, 99.999% 35 trace metals basis), urea (ACS reagent, 99.0-100.5%), thioglycolic acid (TGA, ≥99%), tin(II) 36 chloride dihydrate (SnCl₂·2H₂O, ≥99.995%), lithium bis(trifluoromethanesulfonyl)imide salt 37 (LiTFSI), 4-tert-Butylpyridine (tBP, 98%), and ethylene carbonate (EC, 98%) were purchased 38 from Sigma-Aldrich. Tin (IV) oxide (SnO₂, 12% in H₂O colloidal dispersion) was purchased 39 from Xi'an Yuri Solar Co. Lead(II) iodide (PbI2, 99.99% trace metal basis) was purchased from 40 TCI. Formamidinium iodide (FAI) and *n*-octylammonium iodide (OAI) was purchased from 41 42 Greatcell Solar Materials. Spiro-OMeTAD (99.5%) and FK209 Co(III) TFSI salt (>99%) were 43 purchased from Lumtec.

44

45 Material synthesis

Formamidinium lead triiodide (FAPbI₃) black powder was synthesized by mixing FAI (0.8M concentration) with PbI₂ (1:1 molar ratio) in 2-ME under stirring. The mixture was gradually heated to 120 °C while stirring, and the precipitated FAPbI₃ powder was washed three times with ether. After filtration using a glass filter, the black powder was baked at 150 °C for 30 minutes.

51

52 **PSCs substrate preparation**

FTO glass was cleaned following the RCA-SC2 procedure using blends of H₂O₂, HCl, and 53 H₂O, and subsequently, acetone and IPA were used sequentially in an ultrasonic bath. The 54 chemical bath deposition (CBD) solution was prepared by mixing 625 mg of urea, 625 mL of 55 56 HCl, 12.5 mL of TGA, and 137.5 mg of SnCl₂·2H₂O in 300 mL of DI water. After one edge of the FTO substate was taped with kapton tape to mitigate the deposition of SnO₂, these 57 substrates, along with the CBD solution, were loaded onto a Hellendahl staining glass bath. 58 This reaction bath was stored in an oven at 70 °C for 4–6 hours to reach the target pH, after 59 60 which further cleaning with DI water and IPA was performed sequentially. Lastly, the substrates

61 were annealed at 170 °C for 60 minutes under ambient condition to dry the residual solvent,

62 followed by treating 3 mg/mL KCl in DI water at 3,000 rpm for 30 seconds and annealing at

63 100 °C for 30 minutes.

64

65 **PSCs fabrication**

The whole process of the PSCs fabrication was carried out at controlled dry room (20 °C/20% 66 RH). The perovskite precursor solution was prepared by mixing 1,202 mg FAPbI₃, 35 mol% 67 MACl, and 0.8 mol% MAPbBr3 in a mixture of DMF and DMSO (4:1). The filtered perovskite 68 solution, using a 0.2 µm PVDF filter, was spread over the as-prepared SnO₂ substrate at 7,500 69 rpm for 50 seconds with a ramping duration of 0.1 seconds. During the spin-coating process, 1 70 mL of diethyl ether, serving as an anti-solvent, was dripped after spinning for 13 seconds, 71 72 followed by immediate annealing on a hot plate at 150 °C for 15 minutes. To passivate the surface of the perovskite, 4 mg/mL of octylammonium iodide dissolved in IPA was spin-coated 73 on top of the perovskite film at 3,000 rpm for 30 seconds. After then, the hole-transporting 74 75 layer was deposited by spin-coating a spiro-OMeTAD (Lumtech) solution, containing 3 µL of LiTFSI, at 4,000 rpm for 30 seconds. For the target conditions, an EC-incorporated CB solvent 76 77 at a concentration of 5 mM was utilized to dissolve spiro-OMeTAD. Finally, a gold electrode (80 nm) was deposited by thermal evaporation under a high vacuum of 10^{-6} Torr. 78

79

80 **PSMs fabrication**

For the P1 process, 5×5 cm² and 10×10 cm² FTO substrates were scribed using a picosecond 81 laser (Advanced Optowave, AMT 532) with a scribing width of 25 µm. The substrates were 82 scribed with 10 and 18 strips connected in series at a laser power of 2 W, a speed of 200 mm 83 s^{-1} , and a frequency of 500 kHz. In the following steps for the ETL, a compact TiO₂ (c-TiO₂) 84 solution was prepared by diluting Ti(acac)₂ in EtOH (1:15 v/v %). The TiO₂ solution was then 85 sprayed onto the scribed FTO substrates at 450 °C, and the substrates were subsequently 86 annealed at 450 °C for 1 hour. Next, the diluted SnO₂ nanoparticles were dropped onto the c-87 TiO₂ substrates, and then stored in a vacuum oven at 100 °C for 1 hour. For the perovskite layer 88 deposition, 1,139 mg FAPbI₃, 42.54 mg MACl, 74.68 mg PbI₂ and 17.24 mg MAPbBr₃ were 89 dissolved in 1 mL DMF/DMSO (4:1 v/v %). The perovskite solution was filtered through a 0.2 90 µm PVDF filter and coated onto the as-prepared ETL substrate at 5,000 rpm for 50 seconds 91 with a ramping duration of 0.1 second. During the spin-coating process, 5 mL of diethyl ether, 92 used as an anti-solvent, was dropped after 15 seconds of spinning. This was immediately 93 94 followed by sequential annealing on a hot plate at 150 °C for 15 minutes and then 100 °C for 1 hour. The passivation and HTL fabrication were conducted in the same manner as for the small-95 sized PSCs. The P2 lines (90 µm width) were patterned with a laser power of 0.6 W, a speed of 96 200 mm s⁻¹, and a frequency of 500 kHz. The distance between the P1 and P2 lines was 97 approximately 75 µm. Finally, the Au top electrode was deposited with a thickness of 80 nm. 98

- 99 The P3 process (42 μ m width) was scribed with a laser power of 0.6 W, a speed of 200 nm s⁻¹,
- and a frequency of 500 kHz. The distance between the P2 and P3 was approximately 56 $\mu m.$
- 101

102 Characterization of the spiro-OMeTAD and perovskite films

103 FT-IR spectra were measured using a spectrometer with attenuated total reflection mode (670-104 IR, Varian). UV-visible absorption spectra were measured using a spectrophotometer (Cary 5000, Agilent). ESR spectra were measured using a spectrometer (EMXplus, Bruker Optics). 105 AFM images were obtained with a microscope (Dimension ICON, Bruker Nano Surface). 106 Surface potential was measured using a Kelvin probe force microscope (Nanocute, SII 107 108 NanoTechnology Inc.). The potential was measured using two independent lock-in amplifiers, with the cantilever resonance frequency serving as the feedback. The probe used was a Rh-109 coated Si cantilever with a resonance frequency of 25 kHz. UPS spectra were measured using 110 a spectrometer (ESCALAB 250XI, Thermo Fisher Scientific) at a base pressure of 1.0×10^{-9} 111 Torr with a monochromated Al-Ka X-ray source. XRD patterns of the perovskite films were 112 measured using a diffractometer (D8 ADVANCE, Bruker AXS) equipped with Cu-Ka radiation, 113 $(\lambda = 0.1542 \text{ nm})$ as the X-ray source. 114

115

116 NMR measurements

Solution ¹H and ⁷Li spectra were measured using a 400 MHz FT-NMR spectrometer (AVANCE 117 III HD, Bruker Optics) equipped with a 5 mm BBO probe. A zg30 pulse sequence was used 118 with a 90° pulse width. For ¹H spectra, a recycle delay of 1 second was used, with an acquisition 119 time of 4.0894 seconds at a resonance frequency of 400.22 MHz. For ⁷Li spectra, a recycle 120 delay of 5 seconds was used, with an acquisition time of 3.5127 seconds at a resonance 121 frequency of 155.54 MHz. The total number of scans was 16. ⁷Li-¹H HOESY spectra were 122 measured using a 600 MHz FT-NMR spectrometer (ADVANCE NEO 600, Bruker Optics) 123 equipped with a 5 mm Prodigy probe and a hoesyetgp pulse sequence. A recycle delay of 3.57 124 seconds was used, with a mixing time of 1.83 seconds. The number of scans were 4, with 16 125 dummy scans. 126

127

128 ToF-SIMS measurements

ToF-SIMS profiling measured the depth distribution of ions within the structure of FTO/SnO₂/perovskite/spiro-OMeTAD/Au after light illumination and thermal stress using a spectrometer (ToF-SIMS 5, ION TOF) equipped with a pulsed Bi⁺ cluster ion beam (25 keV and 1 pA). To accomplish the depth profiling measurement, Cs (0.25 keV and 12 nA) and O₂ (0.5 keV, 88 nA) ion beams were utilized for negative and positive modes, respectively. The

sputter size was $250 \times 250 \,\mu\text{m}$, while the analysis area for depth profiling was $50 \times 50 \,\mu\text{m}$.

136 **DMA measurements**

- 137 Glass transition temperature of spiro-OMeTAD was measured using a thermal analyzer (DMA
- 138 Q850, TA Instruments) in stretch mode, with a maximum displacement amplitude of 15 μ m, a 139 vibration frequency of 1 Hz, and a heating rate of 3 °C/min from 30 to 150 °C. Samples were
- 140 prepared using poly(propylene) (PP).
- 141

142 Characterization of PSCs and PSMs

143 Unencapsulated PSCs were measured with a solar simulator (Newport-Oriel 94083A, Class

144 AAA) in conjunction with a Keithley source meter 2400, under ambient conditions ($25 \circ C/20\%$

145 RH). The light intensity was calibrated to AM 1.5G (100 mW/cm²) using a Si-reference cell

146 certified by the National Renewable Energy Laboratory. The conventional *J-V* curves were

147 measured under both forward (from a forward bias (-0.05 V) to a short circuit (1.25 V)) and 148 reverse (from a forward bias (1.25 V) to a short circuit (-0.05 V)) scans with the fixed step

voltage of 100 mV. For PSMs with aperture areas of 25 and 100 cm², the voltage ranges were

fixed at 13 V to -0.1 V and 21 V to -0.1 V under reverse bias, respectively. To mitigate artifacts

induced by scattered light, a non-reflective mask with an aperture area of 0.0803 cm² was used

to shield the active area of the device. EQEs were measured using a quantum efficiency

153 measurement system (QUANTX-300, Newport Co.).

154

155 Characterization of PSCs and PSMs stability

The damp-heat (85 °C/85% RH) stability test was conducted using a temperature & humidity chamber (TH3-PE, Jeio Tech Co. Ltd). The performance of the devices was periodically assessed following their cooling to room temperature. The operational stability test was conducted using a white LED calibrated to AM 1.5G (100 mW/cm²), with the PSCs housed in a home-built sample holder purged with a continuous flow of N₂. *J-V* curves with reverse scans were recorded every hour during the operational test.

162

163 Computational details

164 A. Density functional theory (DFT) calculation

All DFT calculations were performed using DMol³ program^{S1,S2} to investigate the electrostatic potential (ESP) charges, ESP isosurfaces, binding energies, and binding Gibbs free energies. Becke's three-parameter hybrid exchange functional with the Lee–Yang–Parr correlation functional was used to describe the exchange-correlation energy.^{S3,S4} The van der Waals interactions was corrected using Tkatchenko-Scheffler method.^{S5} Spin-polarized calculations were employed, and orbital cut-off distance was set at 5.1 Å. For the geometry optimization, the convergence criteria of energy, force, displacement, and self-consistent field were set to 1 $\times 10^{-5}$ Ha, 0.002 Ha/Å, 0.005 Å, and 1×10^{-6} Ha, respectively. All electron relativistic core treatments and double numerical plus polarization (version 4.4) basis set were adopted to describe the core electrons and the atomic orbital basis set, respectively.

175 The binding energies of Li^+ ion with $(EC)_n$ were calculated by following equation.

176 Binding energy =
$$\frac{E_{\text{Li}^+-(\text{EC})_n} - E_{\text{Li}^+} - n \times E_{\text{EC}}}{n_{\text{EC}}}$$
 (Equation S1)

177 where $E_{\text{Li}^+-(\text{EC})_n}$, E_{Li^+} , E_{EC} , *n*, and n_{EC} are the total energy of Li⁺ ion in complex with (EC)_n, 178 the energy of the Li⁺ ion, the energy of EC molecule, the number of molecules, and the number 179 of EC molecules, respectively.

180 The binding energies of the Li^+ ion with TFSI⁻ anion were calculated by the following equation.

181 Binding energy =
$$E_{\text{total}} - E_{Li^+} - E_{\text{TFSI}}$$
 (Equation S2)

where E_{total} , E_{Li^+} , and E_{TFSI^-} are the total energy of Li⁺ ion with TFSI⁻ anion, the energy of Li⁺ ion, and the energy of TFSI⁻ anion, respectively.

The binding energy of the spiro-OMeTAD⁺⁺ with TFSI⁻ anion was calculated by the following
equation.

186 Binding energy =
$$E_{\text{total}} - E_{\text{spiro-OMeTAD}^{+}} - E_{\text{TFSI}^{-}}$$
 (Equation S3)

187 where E_{total} , $E_{\text{spiro-OMeTAD}^{+}}$, and $E_{\text{TFSI}^{-}}$ are the total energy of spiro-OMeTAD⁺⁺ with TFSI⁻ 188 anion, the energy of spiro-OMeTAD⁺⁺, and the energy of TFSI⁻ anion, respectively.

189 The binding Gibbs free energies (ΔG) of the Li⁺ ion with (EC)_n were calculated by the 190 following equation.

191
$$\Delta G = \frac{G_{\text{Li}^+-(\text{EC})_n} - G_{\text{Li}^+} - n \times G_{\text{EC}}}{n_{\text{EC}}} \qquad (\text{Equation S4})$$

where $G_{\text{Li}^+-(\text{EC})_n}$, G_{Li^+} , G_{EC} , *n*, and n_{EC} are the total energy of Li⁺ ion in complex with (EC)_n, the energy of the Li⁺ ion, the energy of EC molecule, the number of molecules, and the number of EC molecules, respectively.

For the modeling of initial configurations of the Li^+ ion with $(EC)_n$, Monte Carlo (MC) simulations were performed by using Sorption program. The COMPASS III forcefield^{S6} was used in the MC simulations. The maximum loading and the production steps were 1×10^5 . The atom-based summation method with a cut-off distance of 12.5 Å was considered for van der Waals interactions and the Ewald method with a 0.001 kcal/mol accuracy was used for electrostatic interactions.

202 B. Molecular dynamics (MD) simulation

MD simulations were employed to investigate the effect of EC molecules on Li⁺ ion solvation 203 characteristics. We used the atomic charge of each molecule by obtaining ESP charges from 204 the DFT calculations. Moreover, atomic charges of Li⁺ ion and TFSI⁻ anions were scaled using 205 the refractive index of EC (*i.e.*, 1.42) based on previous studies; S7,S8 the scaling factor is 0.704. 206 All MD simulations were performed with the COMPASS III forcefield.^{S6} Atom-based 207 summation method with a cut-off distance of 12.5 Å was considered for van der Waals 208 interactions and particle-particle particle-mesh method with a 0.001 kcal/mol accuracy was 209 used for electrostatic interactions. The NPT ensemble (isothermal-isobaric ensemble, P = 1 atm, 210 T = 25 °C or 85 °C) was simulated for 5 ns using Berendsen thermostat and barostat^{S9} using a 211 1 fs time step. After the NPT simulations, the NVT ensemble (canonical ensemble) was 212 simulated for 40 ns using Berendsen thermostat using a 1 fs time step. After the NVT 213 simulations, the analyses of MD simulations were performed from the 38.5 ns to 40 ns. 214



Fig. S1 (a) Electrostatic potential isosurface of ethylene carbonate (EC). The isovalue is 0.03

e/Å. (b) Model systems and optimized structures for investigating the binding sites of Li⁺ ions 219 in the EC molecule.



Fig. S2 (a) Most thermodynamically stable configurations of Li^+ ion with $(EC)_n$. (b) Binding energies of Li^+ ion with $(EC)_n$, where *n* denotes the number of EC molecules. The mint blue colored bars represent the most thermodynamically stable binding energy in each system.



Fig. S3 Model systems for molecular dynamics simulations based on experimental conditions

228 (*i.e.*, control and target conditions).





Fig. S4 Radial distribution function (RDF) of the Li^+ ion with the TFSI⁻ ion (oxygen atom) and EC (oxygen atom in the C=O bond) under control and target conditions at 25 °C.





Fig. S5 (a) The complex structures of the Li^+ ion with the TFSI⁻ ion and EC molecule, obtained

from molecular dynamics simulations under control and target conditions at 25 °C. (b) Binding energies of the Li^+ ion with the TFSI⁻ ion in the complex structures shown in (a), and the most

thermodynamically stable configuration under each condition at 25 °C. The binding energies

239 were obtained through single-point energy calculations.



- Fig. S6 Geometrically optimized structure and binding energy of spiro-OMeTAD⁺⁺ with TFSI⁻⁻
- 243 ion.



- 245
- Fig. S7 AFM images of as-prepared spiro-OMeTAD films deposited onto the perovskite layer
- 247 for various LiTFSI dopant concentrations while maintaining a fixed *t*BP content of 0 μ L. The
- scale bar is 2 μm.
- 249



Fig. S8 (a) *J-V* curves measured with the FTO/spiro-OMeTAD/Au hole only device for evaluating the conductivity of spiro-OMeTAD films. (b) Electrical conductivities of spiro-OMeTAD films as a function of the LiTFSI dopant concentration for a fixed *t*BP content of 0 μ L.



Fig. S9 *J-V* curves measured with the FTO/spiro-OMeTAD/Au hole only device for evaluating

the conductivity of spiro-OMeTAD films under different concentrations of the EC additive.

259



Fig. S10 UPS spectra of the as-prepared spiro-OMeTAD under the control and target conditions; (a) secondary edge region and (b) valence band edge plotted relative to a gold reference.



Fig. S11 PV performance measured by a photovoltaic certification laboratory (Daegu Techpark,
Republic of Korea). The certified efficiency is 25.51%. Standard reporting condition: AM 1.5G
1000.0 W/m² at 25.0 °C / scan rate (100 mV/s) / voltage range (1.3 V to -0.05 V) / number of
points (100 steps) / aperture area (non-reflective mask with an area of 0.0803 cm²) / connection
(4-wire, rear terminal). Solar simulator: Class AAA, Model 94083A, Serial#: 177 / Lamp
model (62726, Serial#: ZGA213P).



Fig. S12 Statistics of the (a) J_{SC} , (b) V_{OC} , (c) FF, and (d) PCE of the PSCs with the control and target conditions.



Fig. S13 EQE and the integrated J_{SC} for the PSCs with the target conditions (25.97 mA/cm²).



Fig. S14 Photograph showing the separation of sub-cells in the PSMs and related widths for

P1, P2, and P3 lines. The GFF can be calculated by the ratio of active area to aperture area and

determined to be 94.60% and 86.40% for the PSMs with aperture areas of 25 and 100 cm^2 ,

284 respectively.



Fig. S15 Statistics of the PCE of the PSMs with an aperture area of 25 cm², under the control

and target conditions.



Fig. S16 *I-V* curves of the target-PSMs with aperture areas of (a) 25 and (b) 100 cm^2 under both reverse and forward scanning directions.



Fig. S17 PV performance measured by a photovoltaic certification laboratory (Daegu Techpark,

Republic of Korea). The certified efficiency is 22.97%. Standard reporting condition: AM 1.5G 1000.0 W/m² at 25.0 °C / scan rate (100 mV/s) / voltage range (12 V to -0.1 V) / number of points (150 steps) / connection (2-wire, rear terminal). Solar simulator: Class AAA, Model

299 94083A, Serial#: 177 / Lamp model (62726, Serial#: ZGA213P).



302 Fig. S18 PV performance measured by a photovoltaic certification laboratory (Daegu Techpark,

Republic of Korea). The certified efficiency is 21.02%. Standard reporting condition: AM 1.5G
1000.0 W/m² at 25.0 °C / scan rate (100 mV/s) / voltage range (25 V to -0.1 V) / number of
points (200 steps) / connection (2-wire, rear terminal). Solar simulator: Class AAA, Model
94083A, Serial#: 177 / Lamp model (62726, Serial#: ZGA213P).



Fig. S19 Variation of *J-V* curves measured with device of FTO/spiro-OMeTAD/Au under (a)
light illumination and (b) thermal stress at 85 °C, respectively.





313 Fig. S20 ToF-SIMS depth profiles of Li^+ ions in device of FTO/SnO_2 /perovskite/spiro-

314 OMeTAD/Au, before being subjected to light illumination and thermal stress at 85 °C.



Fig. S21 Radial distribution function (left) and coordination number (right) of the Li⁺ ion with EC under different temperature conditions (*i.e.*, 25 °C and 85 °C).



Fig. S22 Binding Gibbs free energies (ΔG) of the Li⁺ ion with (EC)_n under different temperature conditions (*i.e.*, 25 °C and 85 °C).



Fig. S23 XRD patterns of perovskite films. The perovskite films were coated once with spiro-OMeTAD under the control and target conditions, followed by the deposition of a gold electrode. Samples were exposed to (a) light illumination and (b) thermal stress at 85 °C, respectively. To investigate XRD patterns of the perovskite films, spiro-OMeTAD films were removed by washing with chlorobenzene. (c) The ratio of intensity for PbI₂ peak to that for (001) FAPbI₃ peak.



Fig. S24 Photographs showing the perovskite films. The perovskite films were coated once

with spiro-OMeTAD under the control and target conditions, followed by the deposition of a gold electrode. Samples were exposed to light illumination and thermal stress at 85 °C,

337 respectively. After then, spiro-OMeTAD films were removed by washing with CB.



- Fig. S25 Photographs showing the perovskite films. The perovskite films were coated once with spiro-OMeTAD under the control and target conditions, followed by the deposition of a gold electrode. Samples were exposed to simultaneous light illumination and thermal stress at
- 343 85 °C. After then, spiro-OMeTAD films were removed by washing with CB.



Fig. S26 UPS spectra of the spiro-OMeTAD under the control and target conditions; (a, c)
secondary edge region and (b, d) valence band edge plotted relative to a gold reference.
Samples were exposed to light illumination and thermal stress at 85 °C, respectively.



Fig. S27 ToF-SIMS depth profiles of I⁻ ions in device of FTO/SnO₂/perovskite/spiro-OMeTAD/Au, after being subjected to (a) light illumination and (b) thermal stress at 85 °C for 500 hours.



Fig. S28 ToF-SIMS depth profiles of AuI_2^- ions in device of FTO/SnO₂/perovskite/spiro-OMeTAD/Au, after being subjected to (a) light illumination and (b) thermal stress at 85 °C for 500 hours.



Fig. S29 *J-V* curves of control and target PSCs measured from 4 V to -20 V to determine the

362 breakdown voltage.

363



Fig. S30 Thermal stability of the encapsulated PSCs subjected to thermal stress at 85 °C (15%
RH).



Fig. S31 Variation of J-V curves of the (a) control- and (b) target-PSCs under the damp-heat (85 °C/85% RH) conditions.



Fig. S32 Variation of *J-V* curves of the (a) control- and (b) target-PSMs with an aperture area of 25 cm² under the damp-heat (85 °C/85% RH) conditions.



Fig. S33 MPPT of the encapsulated PSCs at (a) 60 °C and (b) 85 °C under 1-sun illumination.

Li ⁺ ion	TFSI ⁻ ion	EC
1200	1200	0
700	700	700
	Li ⁺ ion 1200 700	Li ⁺ ion TFSI ⁻ ion 1200 1200 700 700

Table S1. Number of molecules in model systems for molecular dynamics simulations.

	<i>V</i> ос (V)	J _{SC} (mA/cm ²)	FF (%)	PCE (%)
Control-PSCs	1.162	25.868	80.38	24.16
Target-PSCs	1.180	26.031	83.18	25.56

Table S2. Detailed *J-V* parameters of the PSCs using spiro-OMeTAD under the control and
 target conditions.

Published		Photovoltaic parameters					
year	Materials	Voc (V)	$J_{\rm SC}$ (m Λ /om ²)	FF	PCE	Module	Ref.
2017.06	TBA-TFSI	1.071	22.3	77	18.4	-	ACS Energy Lett. 3, 1677-1682 (2018)
2017.08	Mo(tfd-COCF ₃) ₃	1.07	22.11	76	17.8	-	ACS Energy Lett. 2, 2044-2050 (2017)
2018.09	BMPy-TFSI	1.020	21.17	65.12	14.06	-	<i>Joule</i> 2 , 1800- 1815 (2018)
2018.09	Cu(dpm) ₂ (PF ₆) ₂	1.12	22.8	75	19.3	-	ACS Nano 12 , 10452-10462 (2018)
2020.05	TPFB	1.141	23.44	75.29	20.10	-	ACS Appl. Mater. Interfaces 12 , 23874-23884 (2020)
2020.06	PFPPY	1.12	23.98	79.62	21.38	-	Nano Energy 72 , 104673 (2020)
2021.09	Sb_2S_3	1.132	24.75	79	22.13	-	Sol. RRL 5, 2100622 (2021)
2022.06	POM@MOF	1.11	24.1	80.0	21.5	-	Nano Energy 97 , 107184 (2022)
2022.07	DIC-PBA	1.14	24.29	82.1	22.73	-	<i>Joule</i> 6 , 1689- 1709 (2022)
2022.07	TBMP-TFSI & Spiro- OMeTAD(TFSI) ₂	1.175	25.52	83.88	25.15	-	Science 377 , 495- 501 (2022)
2024.01	IP-TFSI	1.19	25.07	84.35	25.16	20.71% (15.03 cm ²)	Angew. Chem. Int. Ed. 63 , e202316183 (2024)
2024.06	Spiro- OMeTAD(TFSI) _x	1.156	25.59	81.7	24.18	-	Adv. Energy Mater. 14 , 2400456 (2024)
	Ethylene carbonate	1.180	26.031	83.18	25.56	23.22 (25 cm ²) 22.14% (100 cm ²)	This work

Table S3. Detailed *J-V* parameters and materials of previously reported PSCs using *t*BP-free
 spiro-OMeTAD HTLs.

390Table S4. Detailed J-V parameters of the PSMs with an aperture area of 25 cm² using spiro-391OMeTAD under the control and target conditions.

25 cm ²	Voc (V)	Isc (mA)	J _{SC} (mA/cm ²)	FF (%)	РСЕ (%)
Control-PSCs	11.36	60.98	2.439	74.37	20.60
Target-PSCs	11.72	61.87	2.475	80.04	23.22

Table S5. Detailed J-V parameters of the PSMs with an aperture area of 100 cm² using spiro-OMeTAD under the control and target conditions.

100 cm ²	Voc (V)	Isc (mA)	J _{SC} (mA/cm ²)	FF (%)	PCE (%)
Control-PSCs	19.19	116.7	1.351	76.61	19.86
Target-PSCs	20.22	118.6	1.373	79.74	22.14

	Target- PSMs	Scan direction	Voc (V)	Isc (mA)	J _{SC} (mA/cm ²)	FF (%)	PCE (%)	Hysteresis index
	25 cm^2	Reverse	11.72	61.87	2.475	80.04	23.22	0.073
	25 cm-	Forward	11.55	61.75	2.470	75.44	21.52	
	100 cm ²	Reverse	20.22	118.6	1.373	79.74	22.14	0.081
		Forward	20.18	117.0	1.354	74.45	20.34	

Table S6. Detailed *J-V* parameters of the PSMs with the target conditions under both reverse
and forward scanning directions.

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